Analog Power AM4404N

N-Channel 30-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- Fast switching speed

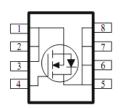
Ty	pical	Apı	plica	tions:

- DC/DC Conversion
- Power Routing
- Motor Drives

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I□ (A)		
30	8.5 @ V _{GS} = 10V	16		
	16 @ V _{GS} = 4.5V	12		







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Drain Current a $T_{A}=$ $T_{A}=$		l _D	16		
		טי	13.2	Α	
Pulsed Drain Current ^b	I _{DM}	60			
Continuous Source Current (Diode Conduction) a		I _S	4.1	Α	
Power Dissipation ^a $ \frac{T_A=25^{\circ}C}{T_A=70^{\circ}C} $		P_{D}	3.1	W	
		' D	2.2	VV	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter			Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	40	°C/W	
Maximum Junction-to-Ambient	Steady State	IXOJA	80	C/VV	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Current	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	25			Α	
Drain Cauras On Basistanas a	r	$V_{GS} = 10 \text{ V}, I_D = 12.5 \text{ A}$			8.5	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$			16	11152	
Forward Transconductance a	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 12.5 \text{ A}$		9		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.05 \text{ A}, V_{GS} = 0 \text{ V}$		0.77		V	
		Dynamic ^b					
Total Gate Charge	Q_g	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		10			
Gate-Source Charge	Q_{gs}	$I_{DS} = 13 \text{ V}, \text{ V}_{GS} = 4.3 \text{ V},$ $I_{D} = 12.5 \text{ A}$		4.1		nC	
Gate-Drain Charge	Q_gd	1D = 12.3 A		4.3			
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 15 \text{ V}, R_1 = 1.2 \Omega,$		7			
Rise Time	t _r	$V_{DS} = 13 \text{ V}, K_L - 1.2 \Omega,$ $I_D = 12.5 \text{ A},$		6		no	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		29		ns	
Fall Time	t _f	V GEN = 10 V, 1 (GEN = 0.22		9			
Input Capacitance	C _{iss}			1399			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		159		pF	
Reverse Transfer Capacitance	C_{rss}			117			

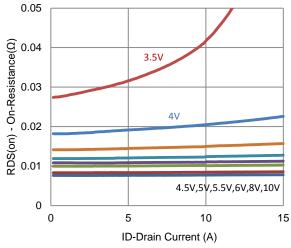
Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

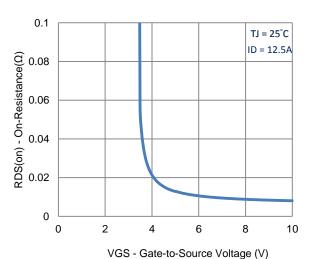
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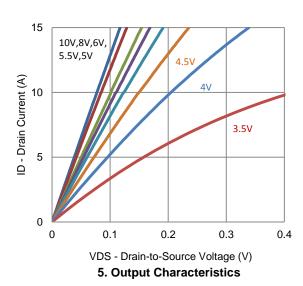
Typical Electrical Characteristics



1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage

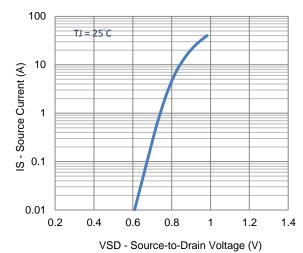


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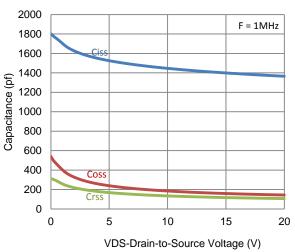
TJ = 25°C

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2. Transfer Characteristics



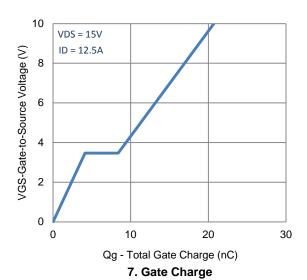
4. Drain-to-Source Forward Voltage

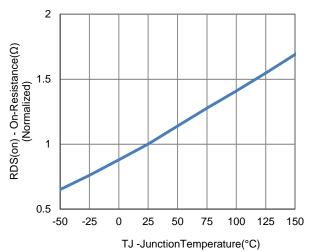


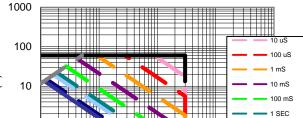
6. Capacitance

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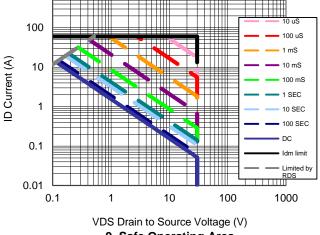
Typical Electrical Characteristics

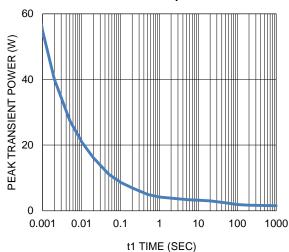






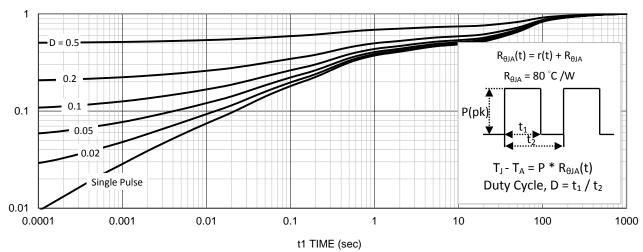
8. Normalized On-Resistance Vs **Junction Temperature**





9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation

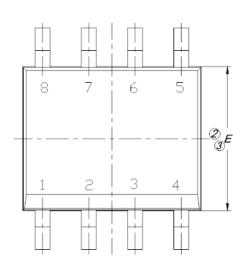


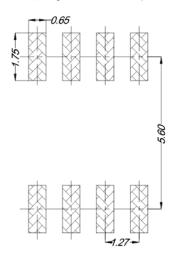
11. Normalized Thermal Transient Junction to Ambient

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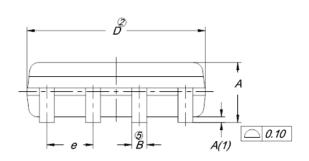
Package Information

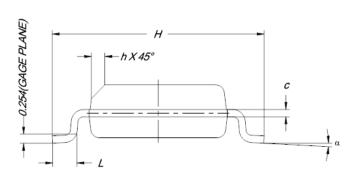
Land Pattern (Only for Reference)





	MILLIMETERS					
DIM.	MIN. NOM.		MAX.			
Α	1.35	1.55	1.75			
A(1)	0.10	0.18	0.25			
В	0.38	0.45	0.51			
С	0.19	0.22	0.25			
D	4.80	4.90	5.00			
Е	3.80	3.90	4.00			
е	1.27 BSC					
Н	5.80	6.00	6.20			
L	0.50	0.72	0.93			
α	0°	4°	8°			
h	0.25	0.38	0.50			





Note:

- All Dimension Are In mm.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- 5. Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.